Level 1: 50 kW DC-DC Converter

Model Number: SPS067B3DD120E

Key Data

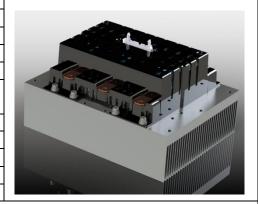
1 Phase Converter Configuration

Rated output: 50kW

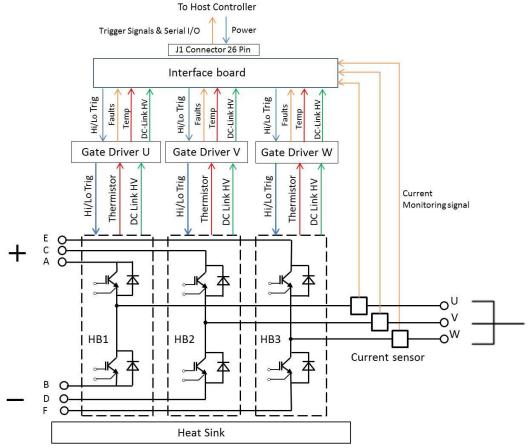
General Information

Standard configuration includes: (3) IGBT Modules, (3) Gate Drive Boards, (3) Current Sensors, Interface Board & Heat Sink

Topology	Single Phase Inverter		
Application / Modulation	Inverter / Sine or Custom		
Load Type	Resistive, Inductive		
Standards	UL 508C		
Cooling	Forced Air (fan optional)		
Markets	Solar, Wind, UPS, Battery Storage, Motor Control,		
	Power Conversion Applications.		
Current Sensors	LEM – HASS 200-S		
IGBT Modules	FUJI – Electric DualXT – 2MBI225VN-120 &-120S		
Gate Drive Boards	AgileSwitch – AS2-EconoDual Electrical		
Interface Board	AgileSwitch – ASI-PS		
Heat Sink	Methode – High Performance Extruded		



SmartPower Stack Topology



*DC link capacitors and Controller Optional

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Note: Operating Conditions:

 $V_{DC_IN} = 680$, $V_{DC_OUT} = 480$, $F_{SW} = 5$ kHz, $cos(\phi) = .9$, airflow = 485 m^3 /hr, air temp = 25°C, $I_{DC_OUT} = 105$ $A_{RMS} = 100$

Electrical Characteristics

DC Link	Notes	Symbol	min	typ	max	unit
DC link Voltage	Continuous Operation	V_{DC}	280		900	V
Max Surge Voltage	2 min, non-operational				1200	V
Overvoltage Shutdown	Configurable		880	900	920	V

AC Data	Notes	Symbol	min	typ	max	unit
Voltage		V _{AC}			635	V_{rms}
Continuous Current	See Typical Operating Conditions	I _{AC}		105	270	A_{rms}
Power Loss	See Typical Operating Conditions	P _{loss}		1800		W
Switching Freq ¹	See Typical Operating Conditions. Max frequency is @ 50°C	F _{SW}		5	10	kHz
Power Factor	Leading or Lagging	Cos(φ)	0		1	
Surge Current	Max for 10 μs				1350	A_{rms}

General Data	Notes	Symbol	min	typ	max	unit
High Voltage IGBT to Heat Sink				3.0		kV AC
High Voltage IGBT to J1 Connector				3.0		kV AC
High Voltage IGBT to J1 Connector –			8.0			mm
Creepage/Clearance						
High Voltage IGBT Connections and			8.0			mm
Circuits to Heat Sink						

Heat Sink Air Cooled/Thermal Data

Data	Notes	Symbol	min	typ	max	unit
Airflow	See Typical Operating Conditions	$\Delta V/\Delta t_{Air}$		485		m³/hr
Air Pressure Drop		ΔP_{Air}		410		Pa
Cooling Air Inlet Temperature	Typical Operating Conditions are supported over this operating range, including Tmax.	T _{inlet}	-25	25	50	°C

Environmental Conditions

Data	Notes	Symbol	min	typ	max	unit
Storage Temp	Non-operational	T _{Stor}	-40		85	°C
Maximum allowed heat sink temperature					90	°C
Ambient Temp	Continuous Operation	T _{Amb}	-25		50	°C
Altitude above sea level	Derated operation possible above Alt Max	Alt			1000	m
Air Pressure	Standard Atmosphere	P _{air}	900		1100	hPa
Humidity	Non-condensing	Rel. F	5		85	%
Pollution Degree				2		
Total Weight				13		kg
Weight w/o Heat Sink				7.6		kg
Dimensions	LxWxH		280	215	165	mm
Heat Sink Dimensions	LxWxH		280	215	80	mm
Torque at AC terminals		M _{AC}	16		20	Nm

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SmartPower Stack 50kW DC-DC L1 Spec Sheet v6 2014-09-03

Level 1: 50 kW DC-DC Converter

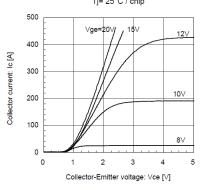
IGBT Module Data - Fuji 2MBI225VN-120 &-120S

Module Absolute Maximum Ratings	Notes	Symbol	min	typ	max	unit
Collector-Emitter Voltage		V_{ces}			1200	V
Gate-Emitter Voltage		$V_{\rm ges}$			±20	V
Collector Current	Continuous	I _c			225	Α
Collector Current	Pulse 1ms	I _{c_pulse}			450	Α
Collector Power Dissipation	1 Device	P _c			1070	W
Junction Temperature	Maximum / Operating	T _j			175/150	°C
Isolation Voltage	Terminals to baseplate, 1 min	V _{iso}			2500	VAC

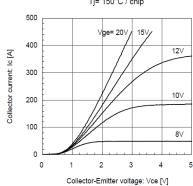
IGBT Data	Notes	Symbol	min	typ	max	unit
Collector-Emitter Saturation voltage	I_c =300A, V_{ge} =15V, T_j = 150°C	V_{ce_sat}		2.6		V
Parameter for linear model	T _j = 25°C	V _{ce1}		1.04		V
Parameter for linear model	T _j = 25°C	R _{ce1}		3.6		mΩ
Parameter for linear model	T _j = 150°C	V _{ce2}		0.91		V
Parameter for linear model	T _j = 150°C	R _{ce2}		6.0		mΩ
Thermal resistance junction to case		R_{thjc}			.14	K/W
Thermal resistance case to heat sink		R _{thch}			.0167	K/W

Diode Data	Notes	Symbol	min	typ	max	unit
Thermal resistance junction to case	For one device	R_{thjc}			.19	K/W
Thermal resistance case to heat sink	For one device	R_{thch}			.0167	K/W

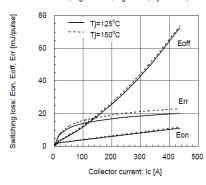




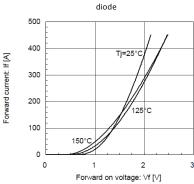
Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip



Switching loss vs. Collector current (typ.) Vcc=600, Vge= \pm 15V, Rg=1.6 Ω , Tj=125°C, 150°C



Forward Current vs. Forward Voltage (typ.)



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External Input/Output Data

Input

DC Link Bus Connections A+, B-, C+, D-, E+, F-

There are 6 DC Link Bus Connections. These connections are positive and negative connections to the 3 Half Bridge (here by referred to as 'HB') sections in the SmartPower Stack.

Item	Description/Value
Bus Connections A+, C+, E+	Positive high voltage bus connections to HI Side collector of each HB
Bus Connections B-, D-, E-	Negative high voltage bus connections to LO Side emitters of each HB
Mounting Holes	M6x1 – 16 mm

Controller/Power to Interface Board - J1

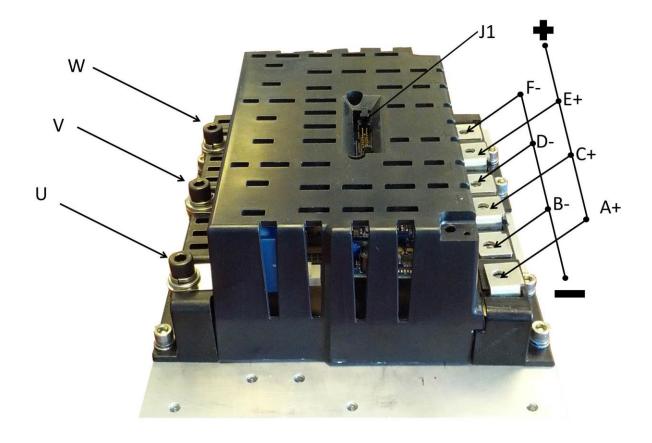
Detailed connection data on previous page.

Output

Connections U, V, W

There are three output connectors. These connectors are located at the center point output of each HB.

Item	Description/Value
Bus Connections U, V, W	High Voltage DC Output
Mounting Holes	M8x1.2 – 25 mm



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Specification for Over Current Protection

For applications requiring fuse protection, the fuse should have the following characteristics:

Category	Notes	Value	Unit
Maximum Fuse Rating Input and Output (A)		200	А
Maximum I ² T		6.5	kA ² s

Controller Interface Data

Data	Notes	Symbol	min	typ	max	unit
Power Voltage Input		V _{in}	13	24	30	V
Power Input ⁽¹⁾	V _{in} = 24V	P _{aux}			30	W
Driver board	See separate spec sheet for details		AS2-Econ	odual Elec	trical	
Input Signal Logic Hi Level	10kΩ to GND, 1nF to GND	V_{in_hi}	11	15	17	V
Input Signal Logic Lo Level		V_{in_lo}	-0.5	.5	2	V
Digital Output Level	Open collector, low=ok, max sink: 15mA	V _{out}	0	-	30	V
Analog Output Format	0-10V, max source 15mA					
DC Voltage Measurement range	DC Voltage corresponds to 0V to +12V	V_{dc_range}	100	-	1000	V
AC Current Measurement range	analog range	I _{ac range}	-	-	+1200	Α
	Current Output analog voltage is -12V to		1200??		??1800	
	+12V		1800?			
Temperature Measurement range	Temperature output voltage corresponds to 0V to +10V	T_{range}	-40	-	150	°C

⁽¹⁾ The Current Input of the 24V supply should be current limited or fused to 3A.

Controller/Power to Interface Board (J1) Connectors Data

J1 Connector PINOUT Descriptions

Pin No	Signal	Pin No	Signal
1	SHIELD	2	BOT-HB1-IN
3	ERROR-HBI-OUT	4	TOP-HB1-IN
5	BOT-HB2-IN	6	ERROR-HB2-OUT
7	TOP-HB2-IN	8	BOT-HB3-IN
9	ERROR-HB3-OUT	10	TOP-HB3-IN
11	OVERTEMP-OUT	12	RESERVED, MUST LEAVE NC
13	VDC-LINK	14	VCC – +24V Supply Voltage
15	VCC – +24V Supply Voltage	16	+15V
17	+15V	18	GND
19	GND	20	TEMP-SENSE-OUT
21	Aux GND	22	I-SENSE1-OUT
23	Aux GND	24	I-SENSE2-OUT
25	Aux GND	26	I-SENSE3-OUT

J1 Connector Hardware

Connector	Туре	Manufacturer Part Number
Ribbon Cable	26 Pins	TE Connectivity 1658622-6
Interface Board	26 Pins	TE Connectivity 5499923-6

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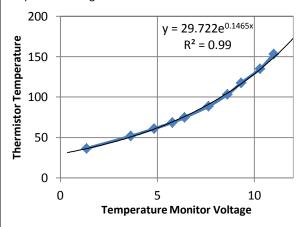
Temperature, Voltage and Current Monitor Output

AgileSwitch **SmartPower Stacks** implement five analog output signals available on J1, on the 26 pin output connector.

Temperature (TEMP-SENSE-OUT PIN 20)

The temperature monitor signal is an analog output voltage with a 0V to 11V range that represents the temperature of the IGBT thermistor in the center IGBT half bridge (HB) leg in the SmartPower Stack. The graph below shows the temperature and output voltage relationship. Frequency response = 100Hz

Note: A reading of 10V corresponding to a 110 °C thermistor temperature will generate a fault and shutdown condition.

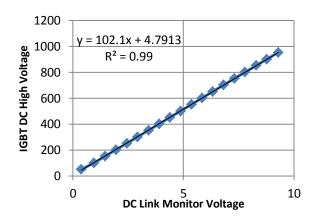


High Voltage (HV) Link (VDC-LINK PIN 13)

The HV monitor is an analog voltage with a range of 0 to 10V. The output voltage represents the voltage on the high side connection of the SmartPower Stack. High Voltage is calculated by the following approximate equation:

$$V_{DC\ LINK} = (102 \times HV_{MONITOR}) + 5V$$

The DC Link Monitor has an accuracy of \pm 1% from 100V to 950V. The chart demonstrates the relationship between analog output and HV Link Monitor Output Voltage. Frequency response = 1Khz



Current (I-SENSE-OUT PINS 22, 24, 26)

The SmartPower Stack has three current monitor signals available for configuration Single Half Bridge Configuration. All three half bridges are triggered in parallel and the total current from all three HB's is indicated by the analog voltage on I-SENSE1-OUT PIN 22 signal. The actual current is calculated by the equation:

$$i_{phase} = 111 \times i_{sv}(x)$$

In addition, the current in HB2 and HB3 is available on I-SENSE2-OUT PIN 24 and I-SENSE3-OUT PIN 26. The output current for these two is the same for the 3 phase configuration:

$$i_{phase} = 37 \times i_{sv}(x)$$

Note: The accuracy of the current sensor is \pm 1.5%. Note that each current sensor has an offset current error of \pm 3A that should be nulled in the system's monitoring software. Frequency response = 10KHz

A current monitor voltage of \pm 10V will generate a fault and shutdown condition.

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Protection / Faults

Fault Table

Fault Condition/Action	Generic Sample Default Trigger Values	Action on IGBT if Active
Desat - HI	>7 Volts for 6.1 µs*	Turn off HI side
Desat – LO	>7 Volts 6.1 μs*	Turn off LO side
HV Overshoot – HI	Not Applicable*	Active Clamping occurs
HV Overshoot – LO	Not Applicable*	Active Clamping occurs
UVLO – HI	<12 Volts	Turn off HI side
UVLO - LO	<12 Volts	Turn off LO side
Cross Latch/Shoot Through	Attempt to turn on both IGBTs simultaneously	Does not allow turn on of inactive IGBT until active is off for 2 μs*
DC Link Overvoltage	900 Volts*	Shut down all IGBTs
Overcurrent	1110 A	Shut down all IGBTs
Over Temperature	>110 °C	Shut down all IGBTs

Certain parameters are configurable (noted by *).

Fault Reporting Pins (Configurable)

Fault Condition/Action	Pin 3	Pin 6	Pin 9	Pin 11
DSAT HB1	Х			
DSAT HB2		Х		
DSAT HB3			Х	
OVERCURRENT HB1	Х	Х	Х	
OVERCURRENT HB2	Х	Х	X	
OVERCURRENT HB3	Х	Х	Х	
TEMP	Х	Х	Х	Х
DC LINK OV	Х	Х	Х	
UVLO	Х	Х	Х	

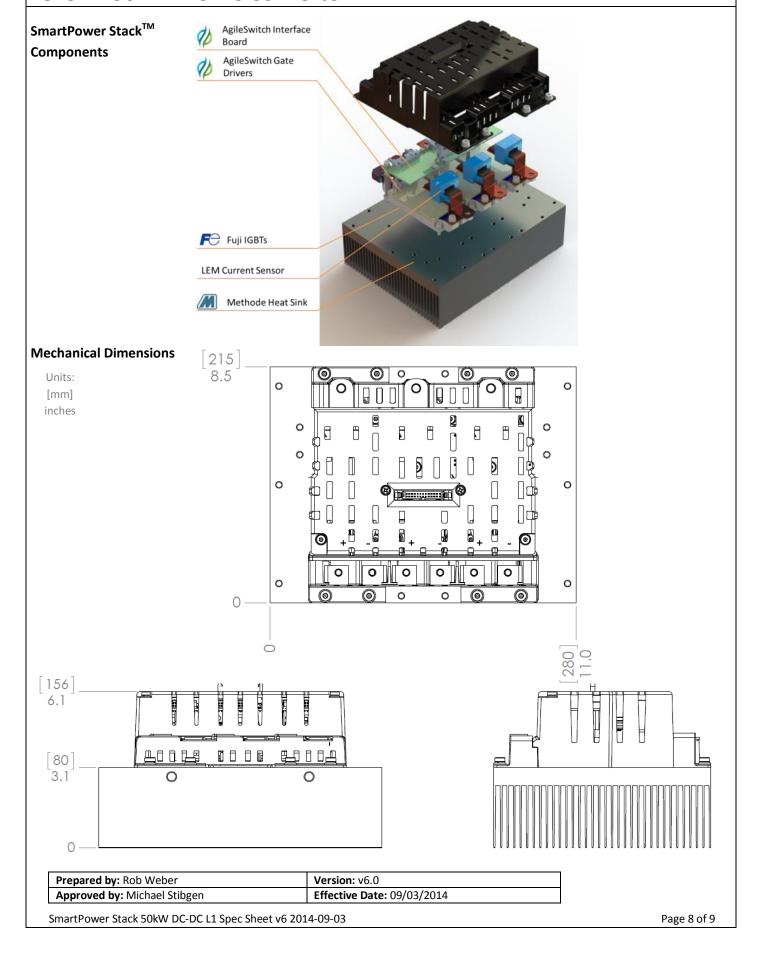
[&]quot;X" = possible to map this fault to this pin

Notes:

- 1. Only 1 fault may be mapped to each pin.
- 2. Though configured as a single Half Bridge, the DC-DC Converter reports if an error has occurred on any of the individual IGBT Modules (Half Bridges) in the system. (Pins 3, 6, 9).
- 3. Temperatures Monitoring is reported from the NTC Thermistor located inside of HB2 in the system (Pin 20).
- 4. Temperature Faults will be triggered for each individual Half Bridge in the system (Pins 3, 6, 9).
- 5. Current Monitoring is reported for each individual Half Bridge in the system (Pins 22, 24, 26).

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SmartPower Stack[™] Consortium

The SmartPower Stack Consortium consists of global leaders in controllers, IGBTs, gate drives, capacitors, bus bar architectures and cooling solutions that have joined to create the industry's first fully integrated, deployment-ready commercial embedded system for high-volume solar, photovoltaic, wind, hybrid electric and electric vehicles, as well as high capacity uninterruptible power supply and efficient motor drive applications.

As part of this effort, National Instruments supplies the controller, I/O, simulation and programming toolset, SBE provides new high performance wound film capacitors, Fuji supplies industry leading IGBTs, AgileSwitch offers leading edge IGBT gate drives and Methode offers state-of-the-art bus bar architectures, thermal management solutions, assembly and test capability.

Together, the five companies are creating fully integrated sub-system solutions for the power electronics industry with the highest performance for energy conversion inverters and convertor systems. This effort represents the industry's first collaboration of best-in-class technologies that are tightly integrated to deliver smart, efficient, reliable and long lasting power conversion.







7401 West Wilson Avenue Chicago, IL 60706-4548 www.methode.com mstibgen@methode.com

1650 Arch Street, #1905 Philadelphia, PA 19103 www.AgileSwitch.com info@AgileSwitch.com 11500 North Mopac Expressway Austin, TX 78759 www.ni.com brian.maccleery@ni.com







50 Northfield Avenue Edison, NJ 08837 www.americas.fujielectric.com

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